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Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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1. Scope

The present specifications shall apply to Sanken silicon rectifier diode, AG01A.

2. Outline

| Туре | Silicon Rectifier Diode (Mesa type) | | | |
|--------------|-------------------------------------|--|--|--|
| Structure | Resin Molded | | | |
| Applications | High Frequency Rectification, etc. | | | |

3. Flammability

UL94V-0 (equipment)

4. Absolute maximum ratings

| No. | Item | Symbol | Unit | Rating | Conditions |
|-----|--------------------------------|------------------|------|----------|-----------------------------|
| 1 | Transient Peak Reverse Voltage | V _{RSM} | V | 600 | |
| 2 | Peak Reverse Voltage | V _{RM} | V | 600 | |
| 3 | Average Forward Current | $I_{F(AV)}$ | А | 0.5 | Tl=130°C Sinewave |
| 4 | Peak Surge Forward Current | I _{FSM} | А | 15 | 10ms. Sinewave, one shot |
| 5 | Junction Temperature | T_j | °C | -40~+150 | |
| 6 | Storage Temperature | T _{stg} | °C | -40~+150 | |

5. Electrical characteristics

| No. | Item | Symbol | Unit | Value | Conditions |
|-----|---|-----------------|-------|----------|---|
| 1 | Forward Voltage Drop | $V_{\rm F}$ | V | 1.8 max. | I _F =0.5A |
| 2 | Reverse Leakage Current | I _R | μΑ | 100 max. | V _R =V _{RM} |
| 3 | Reverse Leakage Current Under High Temperature | ΗI _R | μΑ | 500 max. | V _R =V _{RM} , Ta=100°C |
| 4 | Reverse Recovery Time | trr-1 | nS | 100 max. | I _F =I _{RP} =100mA, 90%Recovery point |
| | | trr-2 | nS | 50 max. | I _F =100mA, I _{RP} =200mA 75% Recovery point |
| 5 | Thermal Resistance | θj-l | °C /W | 22 max. | Between Junction and Lead |



